

**SINGLE PHASE HALL EFFECT LATCH****AH477A****General Description**

The AH477A is an integrated Hall sensor with H-bridged output driver designed for brushless DC motor applications. The device includes an on-chip Hall sensor for magnetic sensing, an amplifier that amplifies the Hall voltage, a comparator to provide switching hysteresis for noise rejection, a bi-directional drivers for sinking and driving large current load. It also includes an internal bandgap regulator to provide temperature compensated bias for internal circuits and allows a wide operating supply voltage range.

Placing the device in a variable magnetic field, if the magnetic flux density is larger than threshold B_{OP} , the DO is turned to sink and DOB is turned to drive. This output state is held until the magnetic flux density reverses and falls below B_{RP} , then causes DO to be turned to drive and DOB turned to sink.

The AH477A is available in TO-94 (SIP-4L) package.

Features

- On-Chip Hall Sensor
- Operating Voltage: 3.5V to 18V
- H-Bridge Output Drivers for Single Coil
- Internal Bandgap Regulator for Temperature Compensation
- Low Output Switching Current Noise
- Operating Temperature: -20°C to 85°C
- Low Profile TO-94 (SIP-4L) Package
- ESD Rating: 6000V (Human Body Model)
- Suitable for PWM Power Supply Control Speed

Applications

- Single-coil Brushless DC Motor
- Single-coil Brushless DC Fan

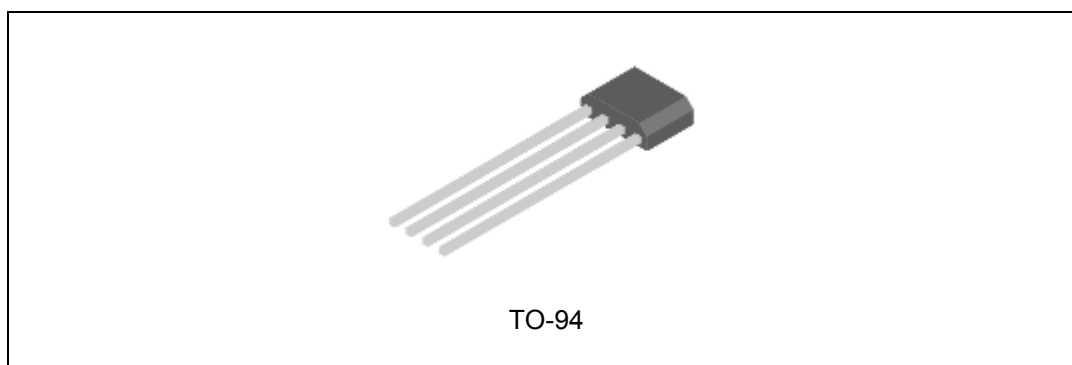


Figure 1. Package Type of AH477A

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AH477A

Pin Configuration

Z4 Package
(TO-94)

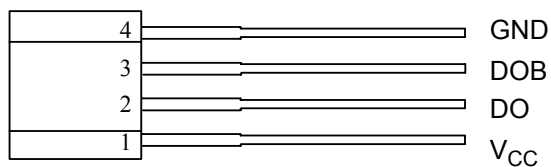


Figure 2. Pin Configuration of AH477A (Front View)

Pin Description

Pin Number	Pin Name	Function
1	V _{CC}	Supply voltage
2	DO	Output 1
3	DOB	Output 2
4	GND	Ground

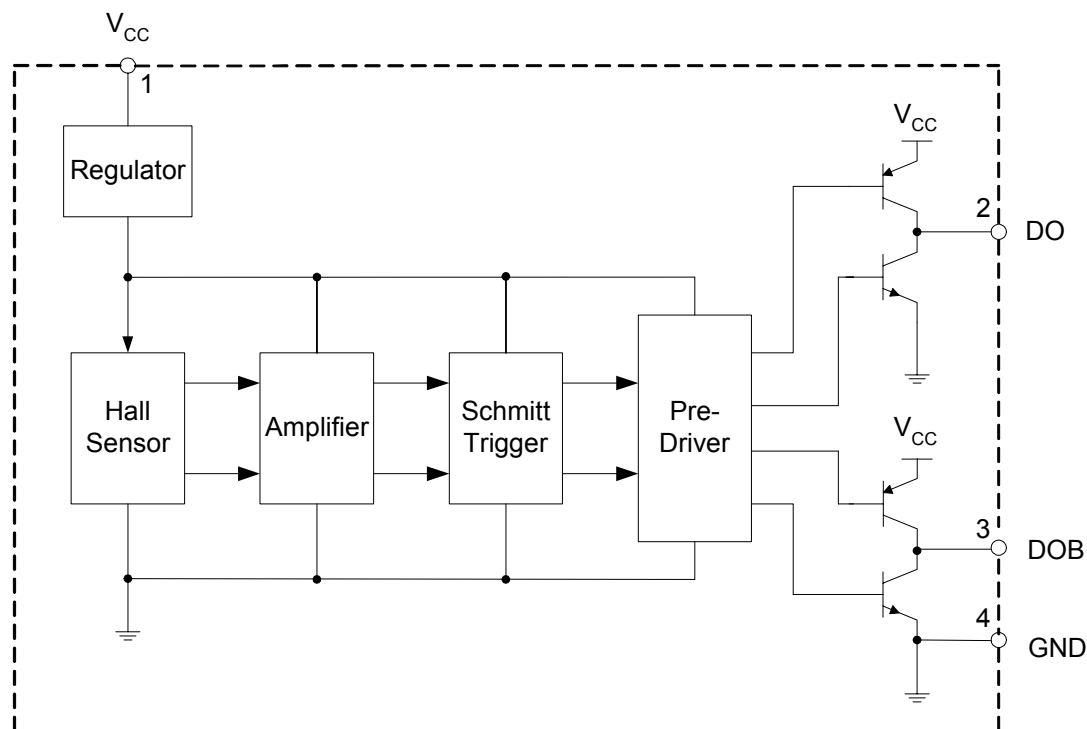
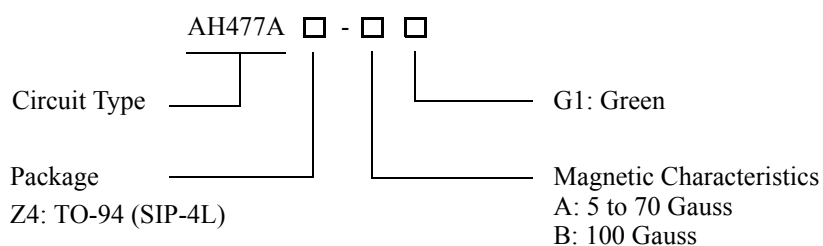
**SINGLE PHASE HALL EFFECT LATCH****AH477A****Functional Block Diagram**

Figure 3. Functional Block Diagram of AH477A

Ordering Information

Package	Temperature Range	Part Number	Marking ID	Packing Type
TO-94	-20 to 85°C	AH477AZ4-AG1	477AZ4-G1	Bulk
		AH477AZ4-BG1	477AZ4-G1	Bulk

BCD Semiconductor's Pb-free products, as designated with "G1" suffix in the part number, are RoHS compliant and green.

**SINGLE PHASE HALL EFFECT LATCH****AH477A****Absolute Maximum Ratings (Note 1)**(T_A=25°C)

Parameter		Symbol	Value	Unit
Supply Voltage		V _{CC}	20	V
Magnetic Flux Density		B	Unlimited	Gauss
Output Current	Continuous	I _O	250	mA
	Hold		300	mA
	Peak (start up)		600	mA
Power Dissipation		P _D	550	mW
Thermal Resistance	Die to atmosphere	θ _{JA}	227	°C/W
	Die to package case	θ _{JC}	49	°C/W
Storage Temperature		T _{STG}	-50 to 150	°C
ESD (Machine Model)			600	V
ESD (Human Body Model)			6000	V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. "Absolute Maximum Ratings" for extended period may affect device reliability.

Recommended Operating Conditions(T_A=25°C)

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V _{CC}	3.5	18	V
Frequency (PWM Power)	f	0.1	25	kHz
Ambient Temperature	T _A	-20	85	°C



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Electrical Characteristics

($T_A=25^{\circ}\text{C}$, $V_{CC}=14\text{V}$, unless otherwise specified)

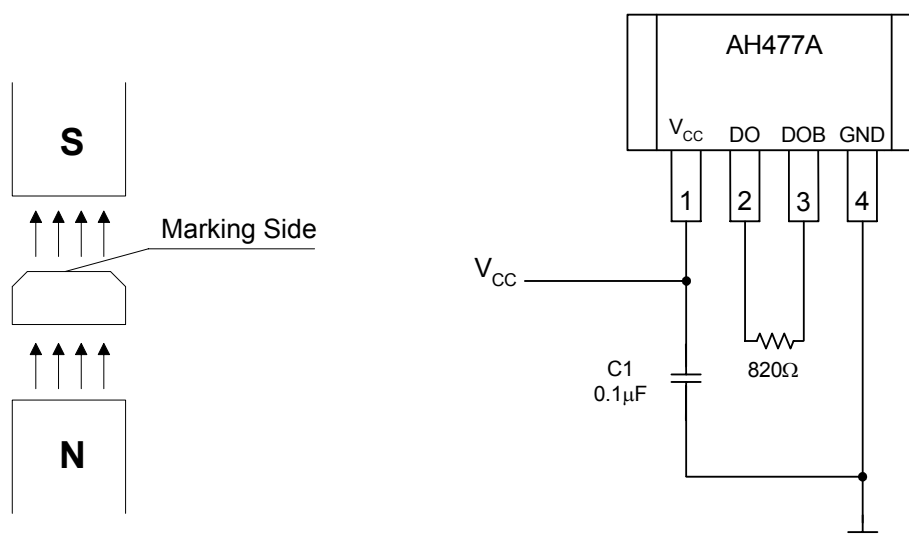
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Output Saturation Voltage (Sink)	V_{SAT}	$V_{CC}=14\text{V}$, $I_O=200\text{mA}$		0.45	0.65	V
Output Saturation Voltage (Drive)		$V_{CC}=14\text{V}$, $I_O=200\text{mA}$	$V_{CC}-1.3$	$V_{CC}-1.0$	V_{CC}	V
Supply Current	I_{CC}	$V_{CC}=20\text{V}$, Output Open		13.5	16	mA
Output Rise Time	t_r	$R_L=820\Omega$, $C_L=20\text{pF}$		0.5	1.0	μs
Output Fall Time	t_f	$R_L=820\Omega$, $C_L=20\text{pF}$		0.5	1.0	μs

Magnetic Characteristics

($T_A=25^{\circ}\text{C}$)

Parameter	Symbol	Grade	Min	Typ	Max	Unit
Operating Point	B_{OP}	A	5		70	Gauss
		B			100	
Releasing Point	B_{RP}	A	-70		-5	Gauss
		B	-100			
Hysteresis	B_{HYS}			70		Gauss

Test Circuit



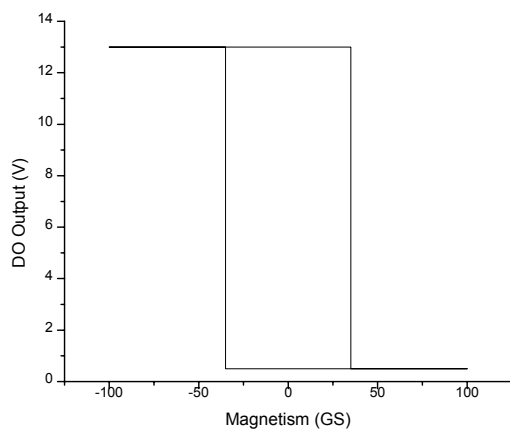
**SINGLE PHASE HALL EFFECT LATCH****AH477A****Magnetic Hysteresis Characteristics**

Figure 4. DO Output vs. Magnetism

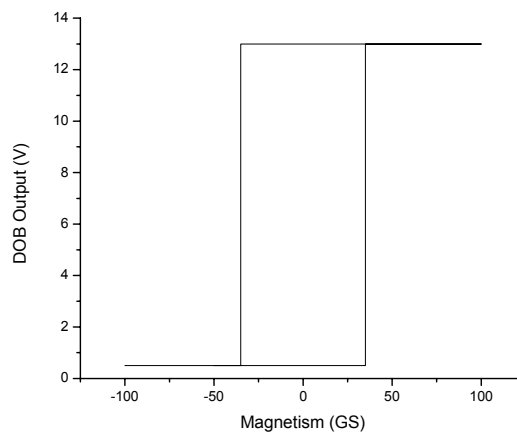


Figure 5. DOB Output vs. Magnetism

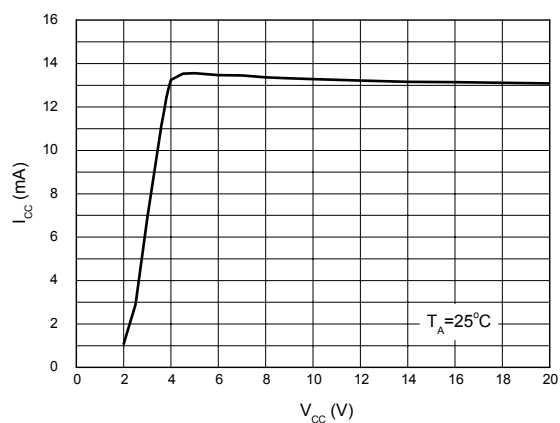
Typical Performance Characteristics

Figure 6. Supply Current vs. Supply Voltage

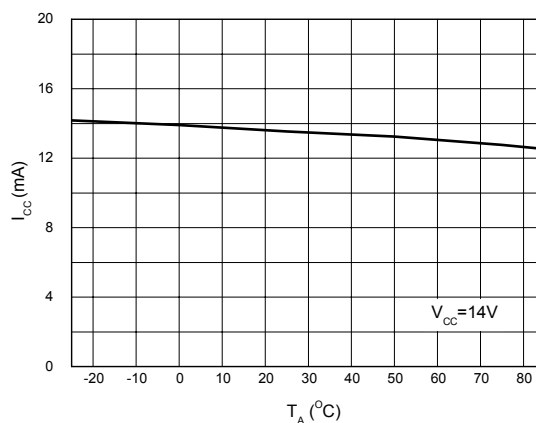


Figure 7. Supply Current vs. Ambient Temperature



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Typical Performance Characteristics (Continued)

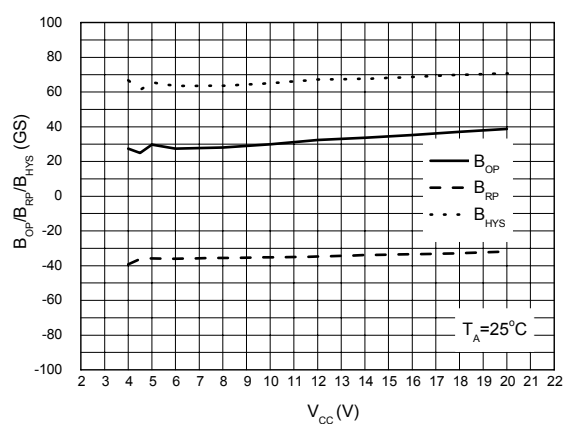


Figure 8. $B_{OP}/B_{RP}/B_{HYS}$ vs. Supply Voltage

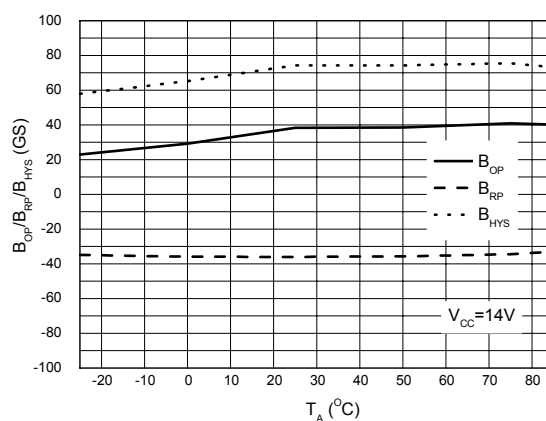


Figure 9. $B_{OP}/B_{RP}/B_{HYS}$ vs. Ambient Temperature

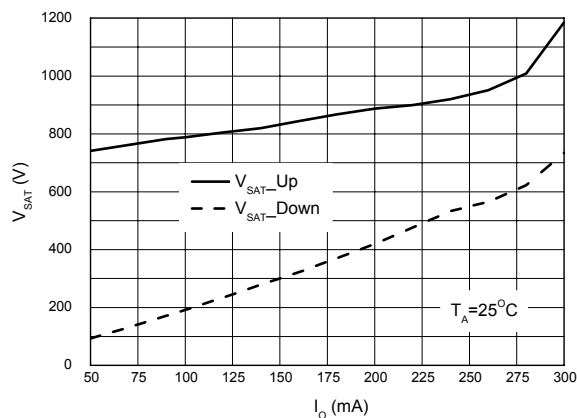


Figure 10. V_{SAT} vs. I_O

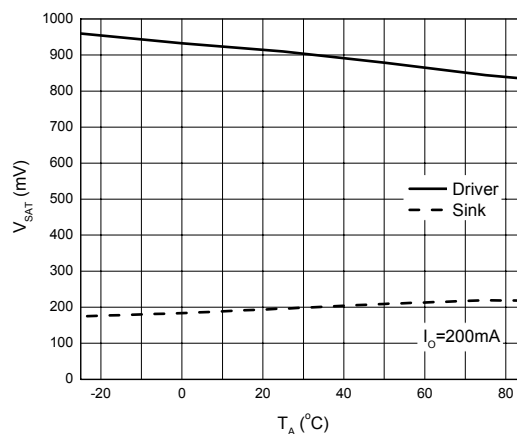


Figure 11. V_{SAT} vs. Ambient Temperature

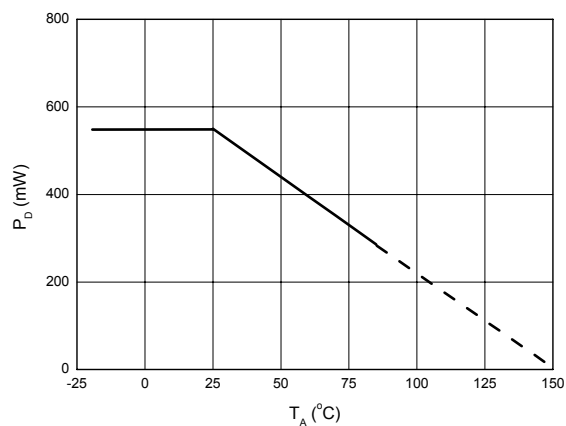
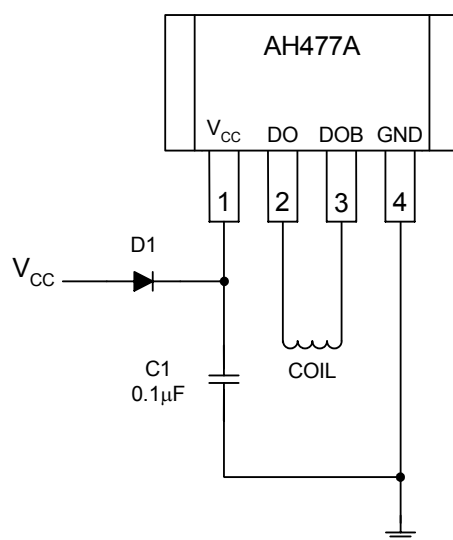
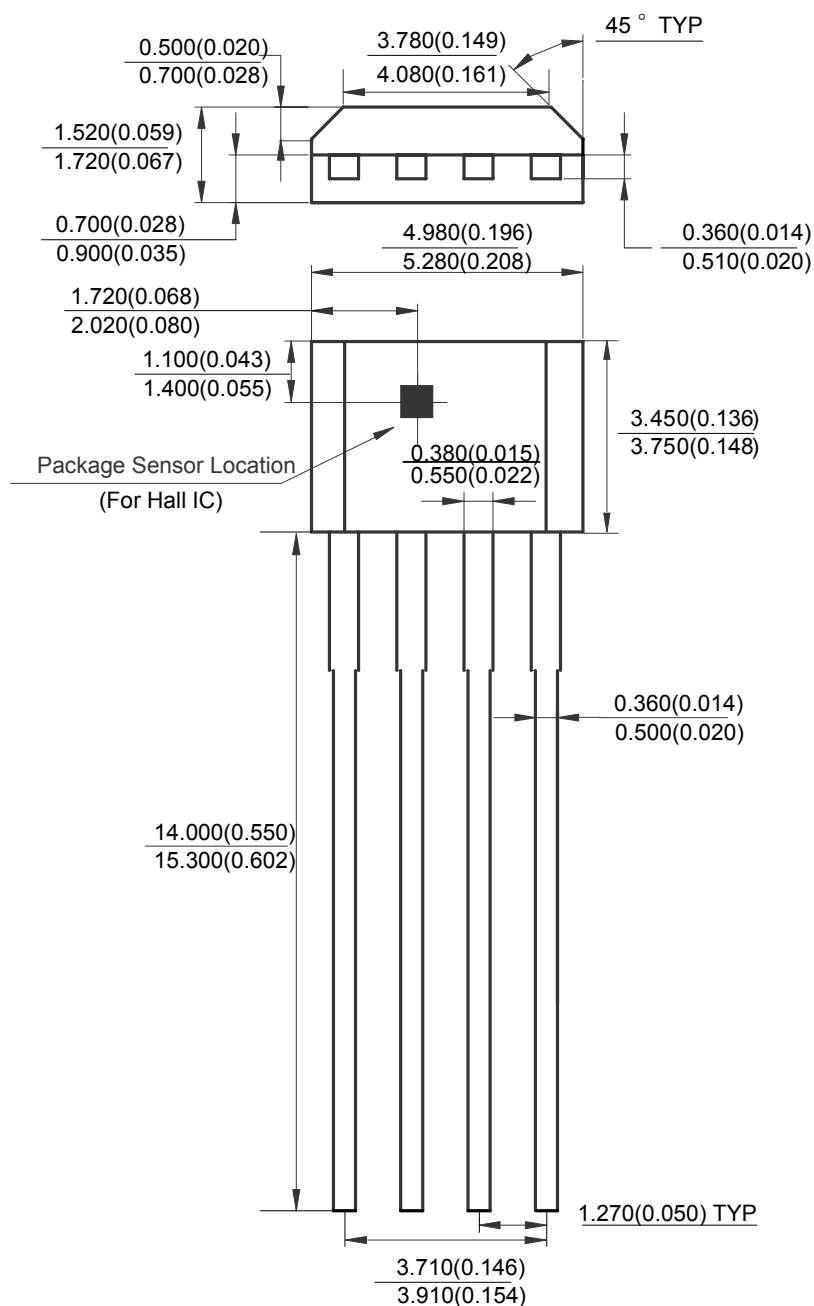
**SINGLE PHASE HALL EFFECT LATCH****AH477A****Typical Performance Characteristics (Continued)**Figure 12. P_D vs. Ambient Temperature**Typical Application**

Figure 13. Typical Application Circuit

**SINGLE PHASE HALL EFFECT LATCH****AH477A****Mechanical Dimensions****TO-94****Unit: mm(inch)**



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